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Efficient Second Harmonic Generation in Nanophotonic Waveguides for Optical Signal Processing

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We report very efficient second harmonic generation in membrane photonic crystal waveguide. The combination of absorption-free material and slow-light enhancement enables a large harmonic generation efficiency. A peak pump power of about 450 mW generates up to 45 μW peak second harmonic power over a broad spectral range. The signal is exploited to demonstrate optical performance monitoring of data at 42 Gb/s.

Harmonic generation and, in particular, Second Harmonic Generation (SHG) is a very important nonlinear effect in optics. Because of their large intrinsic nonlinear susceptibility, semiconductor waveguides have been proposed for efficient frequency conversion and harmonic generation¹. Furthermore, semiconductors offer a powerful technological platform, enabling the integration of photonic circuits. However, SHG is only possible in noncentrosymmetric materials, such as III-Vs or strained More recently, two-dimensional air-cladded silicon². Photonic Crystals (PhC) have emerged as ideal materials for enhancing the light-matter interaction, hence the nonlinear response, owing to their remarkable light confining capability. In particular, Third Harmonic Generation (THG) has been demonstrated in Silicon PhCs³ and, later, exploited to perform optical signal monitoring⁴.

SHG has first been observed in InP PhC cavities⁵ and, more recently, in Silicon PhC, where the much weaker second order susceptibility at the semiconductor surface is enhanced resonantly in suitably designed cavities⁶, however the SHG power is in the pW range. Efficient SHG is possible in waveguides⁷, however this is only true if the phase matching between the fundamental and the second harmonic is ensured, which is notoriously difficult in semiconductors. Indeed, phase-matched optical parametric interactions (including SHG) have been demonstrated owing to the so-called form-birefringence in alternating layers of GaAlAs and oxidized AlAs¹, or, more recently, multi-layers of III-V alloys serving as vertical Bragg mirror⁸ or photonic wires⁹. It must however be pointed out that, as in any resonant interaction, phase matching implies a much reduced bandwidth, depending on the length of the interaction. PhCs only support leaky modes at the second harmonic (SH) with short lifetime, compared to the fundamental mode. As a consequence, the interaction length is much shorter and this tends to reduce the efficiency, with respect to a properly phase matched second harmonic generation process entailing properly waveguided modes. Second harmonic generation has been demonstrated in short (L=17 μm) GaP waveguides¹⁰, but, despite the slow-light enhancement, the efficiency was limited to $5 \times 10^{-7} W^{-1}$.

We demonstrate that the choice of a long waveguide (1.2 mm) enables a larger SHG efficiency $2 \times 10^{-4} W^{-1}$, compared to (hence more than two orders of magnitude larger, roughly scaling with the device length), which we exploit to monitor the quality of high-rate data signals (up to 42.5 Gb/s).

The device is a 1.2 mm-long PhC waveguide made of a self-standing, 180 nm thick membrane of Indium Gallium Phoshpide, which is transparent up to photon energy of 1.9eV ($\lambda \approx 650nm$). The waveguide consist in a missing line defect in the regular triangular lattice of holes; the size and the position of the first row of holes have been modified in order to change the dispersion, as shown in ref.¹¹. The input and output fibre are coupled using tapers¹², shown in *Fig.* 1a. As a result, the total insertion loss (from the input to the output fibre, hence including coupling and waveguide propagation losses) are reduced to a minimum of about 8 dB, away from the slow light regime, with fluctuations from waveguide to waveguide of about 1 dB. Taking into account coupling loss of about 3 dB/facet, we estimate the minimum propaga-



FIG. 1. (a) SEM image of the PhC waveguide with taper at the input; (b) detected SHG spectrum; (c) experimental setup; (d) Optical image of the entire waveguide using a Silicon-CCD, revealing the SHG emission.

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tion loss to less than 2 dB/mm. Thus, in this regime, the pump intensity is weakly attenuated constant over the whole device length.

The optical input are 100 ps pulses generated from a continuous-wave tunable diode laser and a Mach-Zenhder (MZI) modulator. As the peak power is above hundreds of mW, the radiation emitted from the top of the waveguide is easily detected by a standard silicon CCD camera, as shown in *Fig.* 1c,d. The peak at 770 nm of the emitted spectra, collected with a large aperture optical fibre (NA \approx 0.5), is consistent with SHG from the pump input centered at 1540 nm (*Fig.* 1b). Photonic crystal waveguides are highly dispersive and it is therefore expected that the SHG has a complex dependence on the wavelength.

In order to elucidate this point, we consider two different waveguide designs (see ref.¹¹) and we report the SHG signal as a function of the wavelength. This is shown in *Fig.* 2a. First we note that waveguide #1 reveals an abrupt increase of the group index from a minimum of about 6 to 24, while in waveguide #2 the group index increases slowly from 5 to about 10. A slow-light enhancement of the SHG is expected, similarly to what has been reported for Third Harmonic Generation in Photonic Crystals³. More precisely, the theory of SHG in PhC¹³ predicts a quadratic dependence of the SHG efficiency ($\eta = P_{SH}/P_{FF}^2$) on the group index of the fundamental mode n_{qf} , which can be cast as:

$$\eta \propto d_{eff}^2 \omega^2 \frac{n_{gf}^2 n_{gs}}{A_{eff}} \tag{1}$$

Here, d_{eff} is the relevant projection of the second order susceptibility (for GaInP 110 pm/V was reported in the spectral range considered here¹⁴), A_{eff} is the nonlinear cross section related to the field distribution, which coincides with the geometrical cross section in the limit of plane waves. Indeed, Fig. 2c reveals a very strong dependence of the SHG signal on the wavelength, as well as a very strong correlation with the group index. Moreover, this holds for both waveguides, in spite of their different design and dispersion. A more careful inspection of the figure reveals that the peak of efficiency does not coincide with the peak of the group index. This is not surprising. because of the complex dependence of the SHG on various parameters. Moreover, it must be pointed out that a local minimum (-6dB of additional loss, Fig. 2b) of the transmission is located at the local maximum of the group index, thereby compensating for the slow-down enhancement.

This is remarkable, as, given the complex structure of the high frequency bands of the PhC, one would expect a strong dispersive contribution both from A_{eff} and Δk . Yet, a similar correlation of the SHG with the group index has been reported in third harmonic generation in photonic crystal waveguides¹⁵. The reason why the phase mismatch term is not playing a role as crucial as it is common in nonlinear waveguides is elucidated in ref.¹⁵. Here it is shown that a (quasi) phase-matching condition is in-



FIG. 2. (a) Dispersion (group index vs. wavelength) for two different samples (#1,#2); (b) Corresponding transmission spectra; (c) Corresponding detected SHG signal from the top, divided by the square of the coupled pump power.

deed governing the nonlinear interaction. Here, "quasi" is referred to the fact that the interaction length L is typically much shorter than the device length, due to the short propagation length of the Bloch modes at the SH frequency. The short interaction length eases the phase-matching condition. We believe that this also holds for the SHG process in our waveguides.

Quantitative measurements of the SHG efficiency have been performed on sample #3 with pump wavelength set at $\lambda = 1535$ nm and $\lambda = 1550$ nm (slow light regime). A large area Si photodiode, mounted on top of the waveguide with effective collection half angle of 73 degrees, was used to measure the SHG. The coupled input peak power is increased from 10 mW up to about 1W. From 10mW to 100mW a 10 Gbit/s Non Return to Zero (NRZ) Pseudo Random Binary Sequence (PRBS) is set such that the duty cycle is 0.5. Under these conditions, the waveguide dispersion is always negligible. At larger input power, the duty cycle is decreased to 1/20. The SHG peak power (Fig. 3) nicely scales with the square of the pump power over 4 orders of magnitude at least. The deviation from the ideal square law are partly due to the residual drift of the MZ modulator, leading to change in the transmitted power, but also to some thermal effects. The normalized efficiency η , referred to the peak values of the optical power (both for FF and SH), is equal to $10^{-5}W^{-1}$ when the pump wavelength is 1535 nm, and increases to about $2 \times 10^{-4} W^{-1}$ at a wavelength of 1550 nm, hence a 20-fold enhancement, corresponding to roughly a 4-fold enhancement of the group index. This is consistent with

the square scaling discussed above, also considering that losses and the nonlinear cross section (A_{eff}) also play a role here. In particular, propagation losses, which are highly dispersive in PhCs, tend to be large at the local maximum of n_q (1545 nm), as shown in Fig. 3, inset. This explains why a larger efficiency is found at a slightly longer wavelength. The table I provides a summary of recent achievements in SHG in integrated optics. In order to allow a fair comparison, we translate the reported values into the conversion efficiency η , where the pump power refers to the peak value in pulsed experiments. As the devices have very different geometries, we report their length. The maximum SH is reported as a peak value in pulsed experiments. Where available, the SHG bandwidth, referred to the pump wavelength, is also reported. The bandwidth is defined as the tuning range of a CW pump (see Parameswaran *et al.* 7). In the case of cavityenhanced SHG, the bandwidth is λ/Q . Finally, it must be pointed out that external conversion efficiencies have been reported here (except for Abolghasem *et al.*¹⁸). A proper correction for the extraction efficiency is too complicated to be carried out consistently.

In terms of the generated SHG power, the maximum achieved here is 45μ W (peak), which is orders of magnitude larger than any previous results in nanophotonic devices. Only Bragg waveguides¹⁸ enable larger peak SHG, however, the conversion efficiency η is very low. In contrast the normalized efficiency we report here $\eta = 2 \times 10^{-4} W^{-1}$ is 2 orders of magnitude larger than what reported in III-V PhC waveguides¹⁰ and one order of magnitude larger than Si cavities, still offering a large bandwidth (*Fig.* 2b). In semiconductor photonics, only AlGaAs wires and waveguides offer better efficiency, but



FIG. 3. Waveguide # 3. SHG peak power vs. coupled pump peak power for $\lambda_p = 1535$ nm (blue, squares) and $\lambda_p = 1550$ nm (red, crosses). The corresponding square laws $P_{SH} =$ $\eta(n_g)P_{FF}^2$ are shown (dashed lines). The duty cycle is 1/2 at low coupled peak power (below 70 mW) and 1/20 at high peak power. The corresponding dispersion and transmission of the waveguide is shown in the inset.

TABLE I. Comparison of SHG in various integrated optics devices.

Technology	L(mm)	$\eta(W^{-1})$	P_{SH} (peak)	BW	ref.
$LiNbO_3$ wg	60	14	large	${>}0.25~\mathrm{nm}$	7
GaP PhC wg	0.017	5×10^{-7}	1 nW	N.A.	10
InP PhC cav.	N.A.	N.A.	$10 \mathrm{fW}$	N.A.	5
Si PhC cav.	N.A.	4×10^{-5}	50 fW	$50 \mathrm{pm}$	6
$GaN \ \mu$ -ring	N.A.	2×10^{-4}	$2 \ \mu W$	0.5 nm	9
AlGaAs wires	1.2	2×10^{-3}	80 pW	N.A.	16
AlGaAs wg	1.5	7×10^{-3}	1.5 nW	0.3 nm	17
AlGaAs wg	2.2	2×10^{-7}	$190 \ \mu W$	0.8 nm	18
this work	1.2	2×10^{-4}	$45~\mu W$	${\approx}10~\rm{nm}$	

at the expense of a narrower bandwidth. Only Lithium-Niobate waveguide technology enable much larger efficiency and almost 100% conversion⁷, still with a relatively large bandwidth. It must be pointed out, however, that the integration of $LiNbO_3$ waveguides with semiconductor photonics is not straightforward.

The level of the generated optical signal is more than convenient to implement optical performance monitoring of an amplitude-coded signal¹⁹. The main idea is that the second harmonic generation being dependent on the peak to average power ratio, which is easily connected to the noise level, as well as to the dispersion-induced pulse broadening. In the following, we proceed similarly as Corcoran *et al.*, who implemented this concept by exploiting the third harmonic generation in photonic crystals⁴.

We consider a Return to Zero data signal at 42.5 Gb/s with duty cycle = 33%. Under these conditions, the (average) SHG signal is $0.3 \mu W$, 25 dB above the noise floor. This holds when the pump wavelength is between 1530 nm and 1540 nm. In particular, at 1533 nm, the dispersion of the sample used here (wg #4) is about $-0.7ps^2/mm$ and the group index is about 17. The coupled average power is 30 mW. As a comparison, we also considered another wavelength (1560 nm) as the worst case, where the waveguide enters into propagation regime caracterized by strong attenuation and multiple scattering²⁰.

We first characterized the impact of the dispersion. A programmable phase and amplitude optical filter is used to introduce a linear chirp (thereby simulating the propagation through a dispersive link) and an attenuator is used to decrease the Optical Signal to Noise Ratio. Figure 4a reports the dependence of the SHG on the amount of dispersion introduced, while the average input power is kept constant. As expected, this results into a pronounced decrease of the SHG signal. Interestingly, we observe a periodic behavior with the dispersion, which is due to the temporal Talbot effect^{19,21}, thereby implying that the pulse train re-emerges again from a highly dispersed signal.

The impact of the dispersion on the SHG process has been modelled, with remarkable agreement with the ex-



FIG. 4. Waveguide #4. Dependence of the SHG signal on the link dispersion (a) and on the optical signal to noise ratio (b). The signal center wavelength is either 1533 nm (circles) or 1560 nm (triangles).

perimental results, in particular at 1533 nm. The measurement at longer wavelength (1560 nm) deviates from the model, which is not surprising as the waveguide has very bad propagation properties here. Yet the plot keeps its bell-like shape. Fig. 4b connects the SHG signal to the optical SNR, the input average power being constant. The same monotonic increase of the SHG signal with the OSNR is observed independently on the wavelength, e.g. over the whole telecom C-band. In ref.⁴ similar measurements have been performed with a sensitive photodiode which detected a monitoring signal level of about 10pW, whereas our GaInP waveguide generates 300nW (average) from a roughly similar input power level. We infer therefore that the monitoring of signals with -20 dB lower power level should be possible, e.g. with peak power in the 1 mW range.

In conclusion, we report broadband and efficient SHG (45 μW , with 450 mW coupled peak power and with 3dB bandwidth of about 10 nm) in a Photonic Crystal waveguide. The normalized conversion efficiency is $2 \times 10^{-4} W^{-1}$, which, owing to the very strong optical confinement and the slow-light enhancement, is very high for a nanophotonic device. The SHG signal has been used to monitor the OSNR and the chromatic dispersion of a high bit rate (42.5 Gb/s RZ) signal over the entire C-band.

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